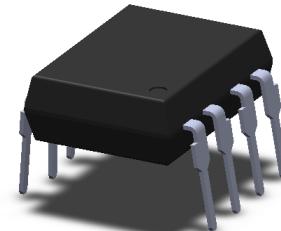


**Features**

- High speed 1Mbit/s
- High isolation voltage between input and output ( $V_{iso}=5000$  Vrms )
- Guaranteed performance from 0 °C to 70 °C
- Wide operating temperature range of -55 °C to 100 °C
- Pb free and RoHS compliant
- UL approved (No. 214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CSA approved (No. 2037145)

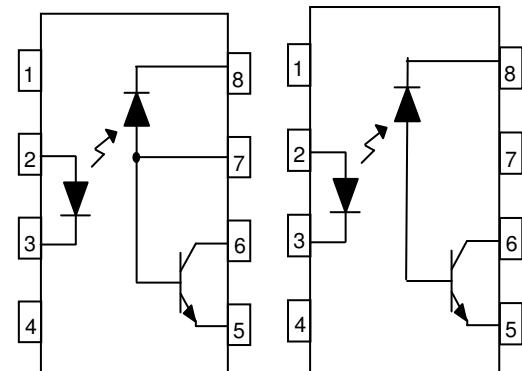
Schematic**Description**

The ELW135, ELW136 and ELW4503 devices each consist of an infrared emitting diode, optically coupled to a high speed photo detector transistor. A separate connection for the photodiode bias and output-transistor collector increase the speed by several orders of magnitude over conventional phototransistor couplers by reducing the base-collector capacitance of the input transistor.

The devices are packaged in an 8-pin DIP wide body package and available in wide-lead spacing and SMD option.

**Applications**

- Line receivers
- Telecommunication equipments
- Power transistor isolation in motor drives
- Replacement for low speed phototransistor photo couplers
- Feedback loop in switch-mode power supplies
- Home appliances
- High speed logic ground isolation

ELW135 / ELW136ELW4503Pin Configuration

- |                  |                  |
|------------------|------------------|
| 1. No Connection | 1. No Connection |
| 2. Anode         | 2. Anode         |
| 3. Cathode       | 3. Cathode       |
| 4. No Connection | 4. No Connection |
| 5. Gnd           | 5. Gnd           |
| 6. Vout          | 6. Vout          |
| 7. $V_B$         | 7. No Connection |
| 8. $V_{CC}$      | 8. $V_{CC}$      |

Pin Configuration

- |                  |                  |
|------------------|------------------|
| 1. No Connection | 1. No Connection |
| 2. Anode         | 2. Anode         |
| 3. Cathode       | 3. Cathode       |
| 4. No Connection | 4. No Connection |
| 5. Gnd           | 5. Gnd           |
| 6. Vout          | 6. Vout          |
| 7. No Connection | 7. No Connection |
| 8. $V_{CC}$      | 8. $V_{CC}$      |

**Absolute Maximum Ratings ( $T_a=25^\circ\text{C}$ )**

Parameter		Symbol	Rating	Unit
Input	Forward current	$I_F$	25	mA
	Peak forward current (50% duty, 1ms P.W)	$I_{FP}$	50	mA
	Peak transient current ( $\leq 1\mu\text{s}$ P.W,300pps)	$I_{Ftrans}$	1	A
	Reverse voltage	$V_R$	5	V
	Power dissipation	$P_{IN}$	45	mW
Output	Power dissipation	$P_O$	100	mW
	Emitter-Base reverse voltage	$V_{EBR}$	5	V
	Base current	$I_B$	5	mA
	Average Output current	$I_{O(AVG)}$	8	mA
	Peak Output current	$I_{O(PK)}$	16	mA
	Output voltage	$V_O$	-0.5 to 20	V
	Supply voltage	$V_{CC}$	-0.5 to 30	V
	Isolation voltage *1	$V_{ISO}$	5000	V rms
Operating temperature		$T_{OPR}$	-55 ~ +100	°C
Storage temperature		$T_{STG}$	-55 ~ +125	°C
Soldering temperature *2		$T_{SOL}$	260	°C

Notes

\*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2, 3, 4 are shorted together, and pins 5, 6, 7, 8 are shorted together.

\*2 For 10 seconds.

**Electrical Characteristics ( $T_A=0$  to  $70^\circ\text{C}$  unless specified otherwise)**
**Input**

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Conditions
Forward voltage	$V_F$	-	1.45	1.8	V	$I_F = 16\text{mA}$
Reverse Voltage	$V_R$	5.0	-	-	V	$I_R = 10\mu\text{A}$
Temperature coefficient of forward voltage	$\Delta V_F/\Delta T_A$	-	-1.9	-	mV/°C	$I_F = 16\text{mA}$

**Output**

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Conditions
Logic High Output Current	$I_{OH}$	-	0.001	0.5	$\mu\text{A}$	$I_F=0\text{mA}, V_O=V_{CC}=5.5\text{V}, T_A=25^\circ\text{C}$
		-	0.01	1		$I_F=0\text{mA}, V_O=V_{CC}=15\text{V}, T_A=25^\circ\text{C}$
		-	-	50		$I_F=0\text{mA}, V_O=V_{CC}=15\text{V}$
Logic Low Supply Current	$I_{CCL}$	-	110	200	$\mu\text{A}$	$I_F=16\text{mA}, V_O=\text{Open}, V_{CC}=15\text{V}$
Logic High Supply Current	$I_{CCH}$	-	0.01	1	$\mu\text{A}$	$I_F=0\text{mA}, V_O=\text{Open}, V_{CC}=15\text{V}, T_A=25^\circ\text{C}$
		-	-	2		$I_F=0\text{mA}, V_O=\text{Open}, V_{CC}=15\text{V}$

\* Typical values at  $T_A = 25^\circ\text{C}$

**Transfer Characteristics ( $T_A=0$  to  $70^\circ\text{C}$  unless specified otherwise)**

Parameter		Symbol	Min.	Typ.*	Max.	Unit	Conditions
Current Transfer Ratio	ELW135	CTR	7	-	50	%	$I_F = 16\text{mA}, V_O = 0.4\text{V}, V_{CC} = 4.5\text{V}, T_A = 25^\circ\text{C}$
	ELW136 ELW4503		19	-	50		
	ELW135		5	-	-		$I_F = 16\text{mA}, V_O = 0.5\text{V}, V_{CC} = 4.5\text{V}$
	ELW136 ELW4503		15	-	-		
Logic Low Output Voltage	ELW135	V <sub>OL</sub>	-	0.18	0.4	V	$I_F = 16\text{mA}, I_O = 1.1\text{mA}, V_{CC} = 4.5\text{V}, T_A = 25^\circ\text{C}$
	ELW136 ELW4503		-	0.25	0.4		$I_F = 16\text{mA}, I_O = 3\text{mA}, V_{CC} = 4.5\text{V}, T_A = 25^\circ\text{C}$
	ELW135		-	-	0.5		$I_F = 16\text{mA}, I_O = 0.8\text{mA}, V_{CC} = 4.5\text{V}$
	ELW136 ELW4503		-	-	0.5		$I_F = 16\text{mA}, I_O = 2.4\text{mA}, V_{CC} = 4.5\text{V}$

\* Typical values at  $T_A = 25^\circ\text{C}$

**Switching Characteristics ( $T_A=0$  to  $70^\circ\text{C}$  unless specified otherwise,  $I_F=16\text{mA}$ ,  $V_{CC}=5\text{V}$ )**

Parameter		Symbol	Min.	Typ.*	Max.	Unit	Conditions	
Propagation Delay Time to Logic Low (Fig.8)	ELW135	TPHL	-	0.36	1.5	$\mu\text{s}$	$R_L=4.1\text{K}\Omega$ , $T_A=25^\circ\text{C}$	
			-	-	2.0		$R_L=4.1\text{K}\Omega$	
	ELW136 ELW4503		-	0.32	0.8		$R_L=1.9\text{K}\Omega$ , $T_A=25^\circ\text{C}$	
			-	-	1.0		$R_L=1.9\text{K}\Omega$	
Propagation Delay Time to Logic High (Fig.8)	ELW135	TPLH	-	0.45	1.5	$\mu\text{s}$	$R_L=4.1\text{K}\Omega$ , $T_A=25^\circ\text{C}$	
			-	-	2.0		$R_L=4.1\text{K}\Omega$	
	ELW136 ELW4503		-	0.25	0.8		$R_L=1.9\text{K}\Omega$ , $T_A=25^\circ\text{C}$	
			-	-	1.0		$R_L=1.9\text{K}\Omega$	
Common Mode Transient Immunity at Logic High (Fig.9) <sup>3</sup>	ELW135	CM <sub>H</sub>	1,000	-	-	$\text{V}/\mu\text{s}$	$I_F = 0\text{mA}$ , $V_{CM}=10\text{Vp-p}$ , $R_L=4.1\text{K}\Omega$ , $T_A = 25^\circ\text{C}$	
	ELW136		1,000	-	-		$I_F = 0\text{mA}$ , $V_{CM}=10\text{Vp-p}$ , $R_L=1.9\text{K}\Omega$ , $T_A = 25^\circ\text{C}$	
	ELW4503		15,000	20,000			$I_F = 0\text{mA}$ , $V_{CM}=1500\text{Vp-p}$ , $R_L=1.9\text{K}\Omega$ , $T_A = 25^\circ\text{C}$	
Common Mode Transient Immunity at Logic Low (Fig.9) <sup>3</sup>	ELW135	CM <sub>L</sub>	1,000	-	-	$\text{V}/\mu\text{s}$	$I_F = 0\text{mA}$ , $V_{CM}=10\text{Vp-p}$ , $R_L=4.1\text{K}\Omega$ , $T_A = 25^\circ\text{C}$	
	ELW136		1,000	-	-		$I_F = 0\text{mA}$ , $V_{CM}=10\text{Vp-p}$ , $R_L=1.9\text{K}\Omega$ , $T_A = 25^\circ\text{C}$	
	ELW4503		15,000	20,000			$I_F = 0\text{mA}$ , $V_{CM}=1500\text{Vp-p}$ , $R_L=1.9\text{K}\Omega$ , $T_A = 25^\circ\text{C}$	

\* Typical values at  $T_A = 25^\circ\text{C}$

### Typical Performance Curves

Figure 1. Forward Current vs Forward Voltage

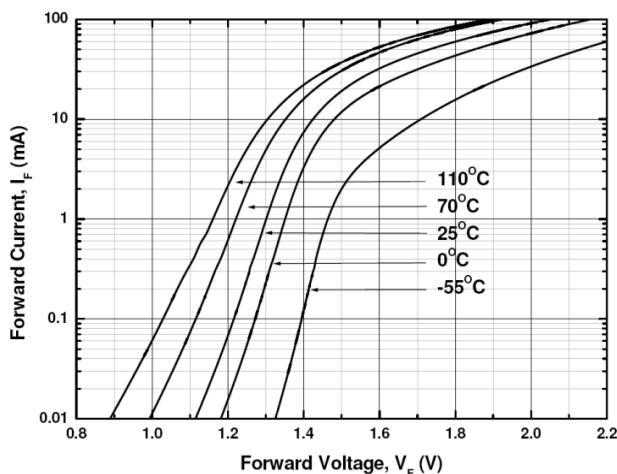


Figure 3. Current Transfer Ratio vs  
Ambient Temperature

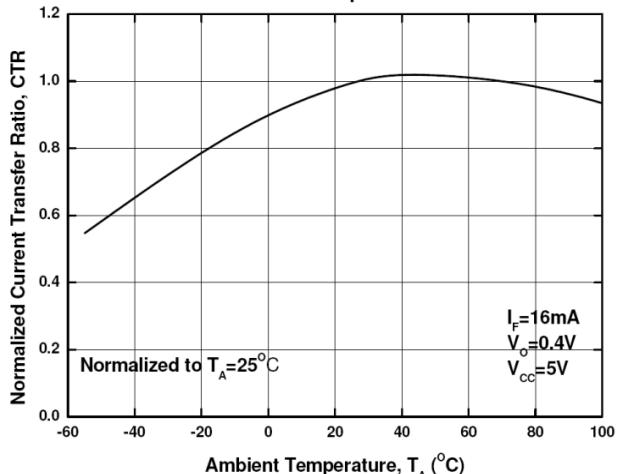


Figure 5. Logic High Output Current  
vs Ambient Temperature

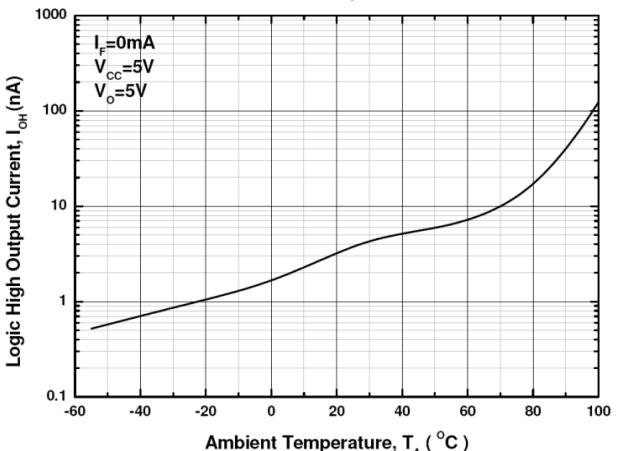


Figure 2. Current Transfer Ratio vs Forward Current

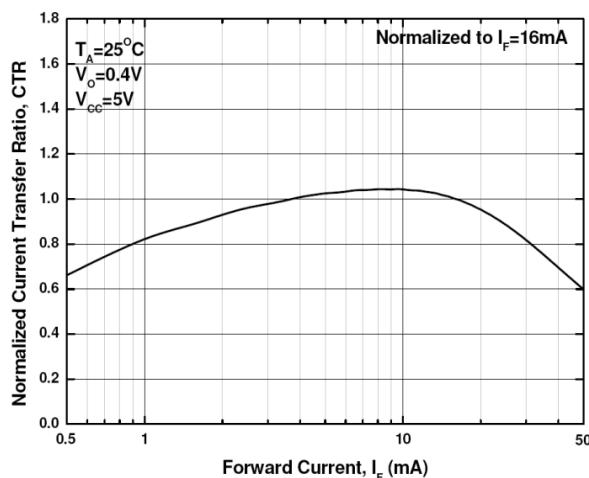


Figure 4. Output Current vs Output Voltage

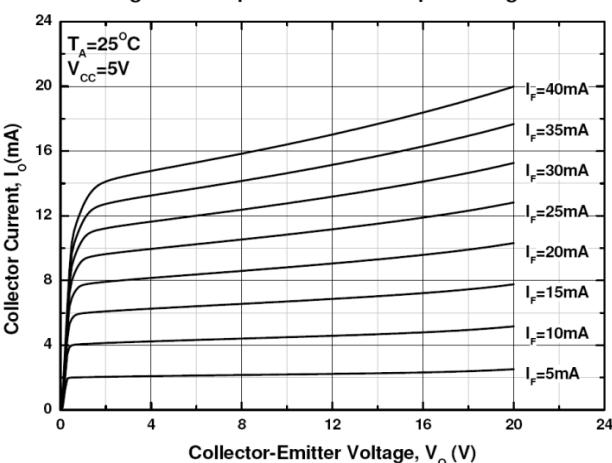


Figure 6. Propagation Delay vs. Load Resistance

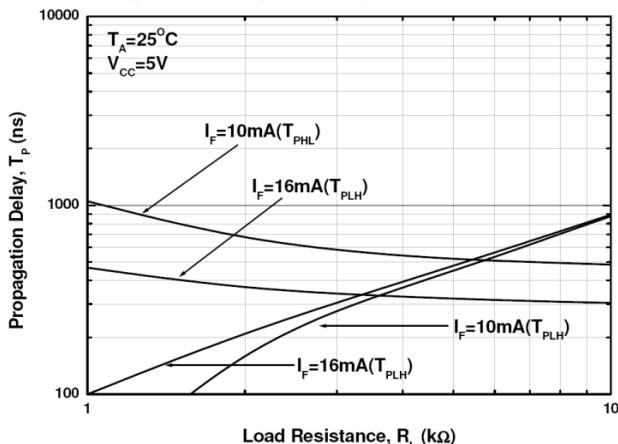


Figure 7. Propagation Delay vs. Temperature

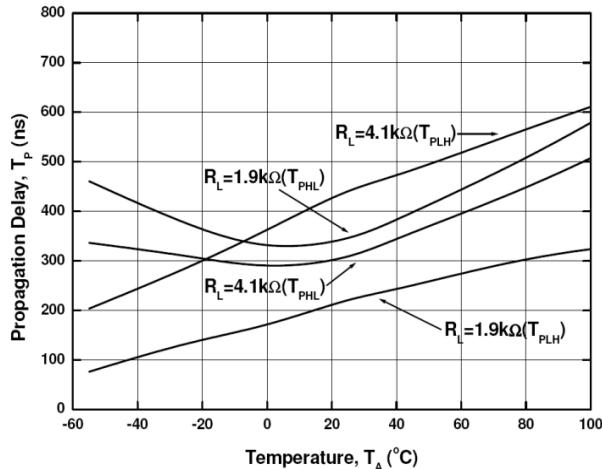


Figure 8 Switching Time Test Circuit & Waveform

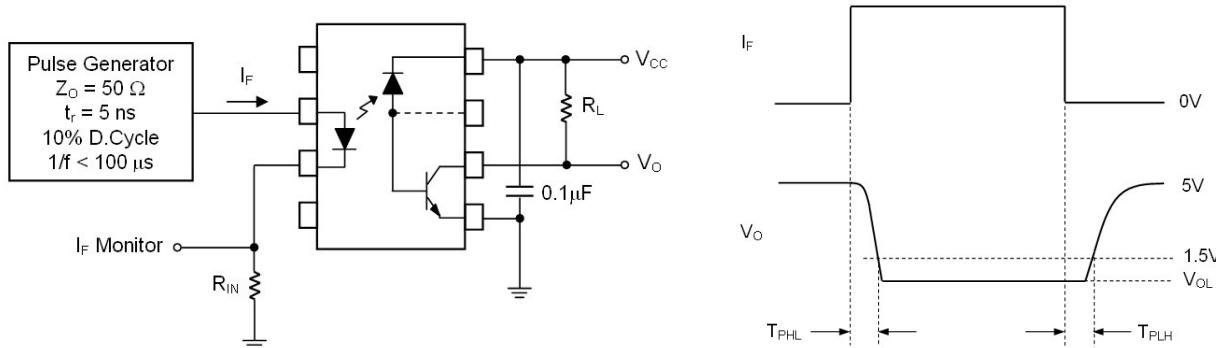
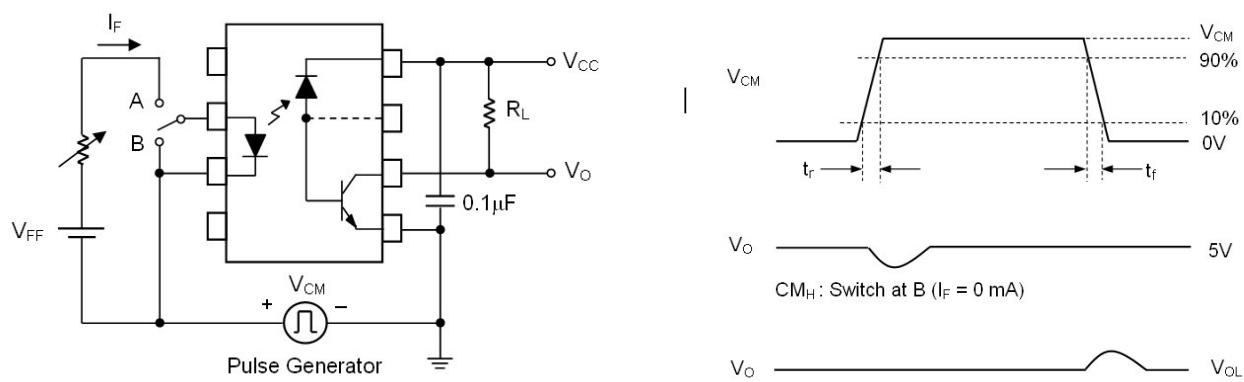


Figure 9 Transient Immunity Test Circuit &



**Note:**

\*3 Common mode transient immunity in logic high level is the maximum tolerable (positive)  $dV_{CM}/dt$  on the leading edge of the common mode pulse signal  $V_{CM}$ , to assure that the output will remain in a logic high state (i.e.,  $V_O > 2.0V$ ). Common mode transient immunity in logic low level is the maximum tolerable (negative)  $dV_{CM}/dt$  on the trailing edge of the common mode pulse signal,  $V_{CM}$ , to assure that the output will remain in a logic low state (i.e.,  $V_O < 0.8V$ ).



## 8 PIN DIP WIDE BODY HIGH SPEED 1Mbit/s TRANSISTOR PHOTOCOUPLER

ELW135 ELW136  
ELW4503

### Order Information

#### Part Number

**ELW13XY(Z)-V**

or

**ELW4503Y(Z)-V**

#### Note

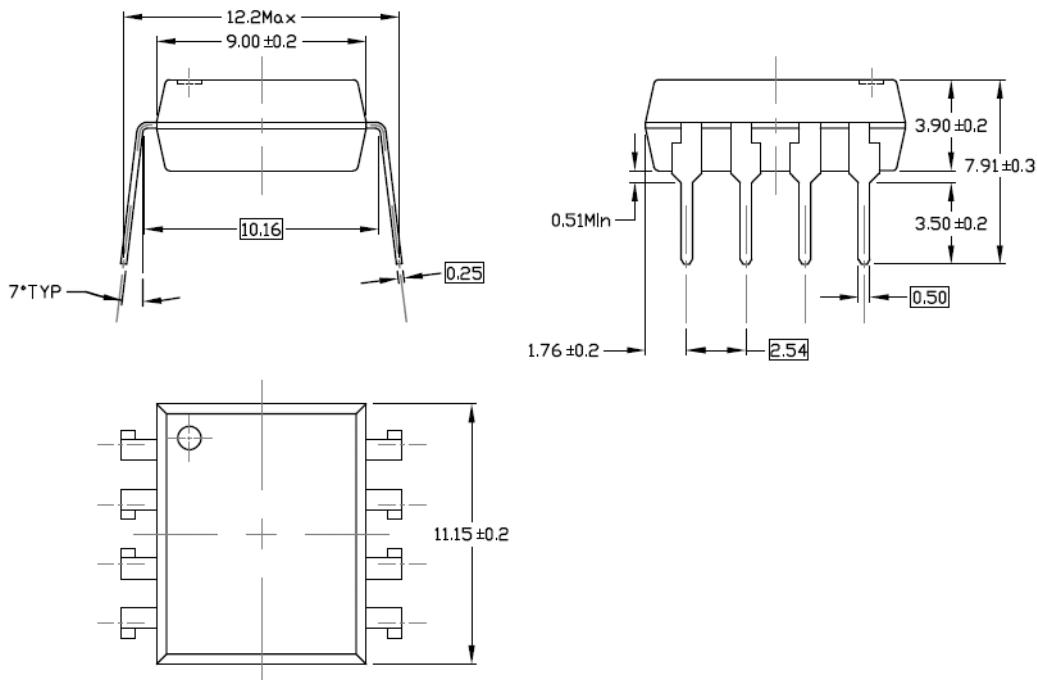
- X = Part No. (X = 5 or 6)
- Y = Lead form option (S or none)
- Z = Tape and reel option (TA, TB or none)
- V = VDE (optional)

Option	Description	Packing quantity
None	Standard DIP-8	45 units per tube
M	Wide lead bend (0.4 inch spacing)	45 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel

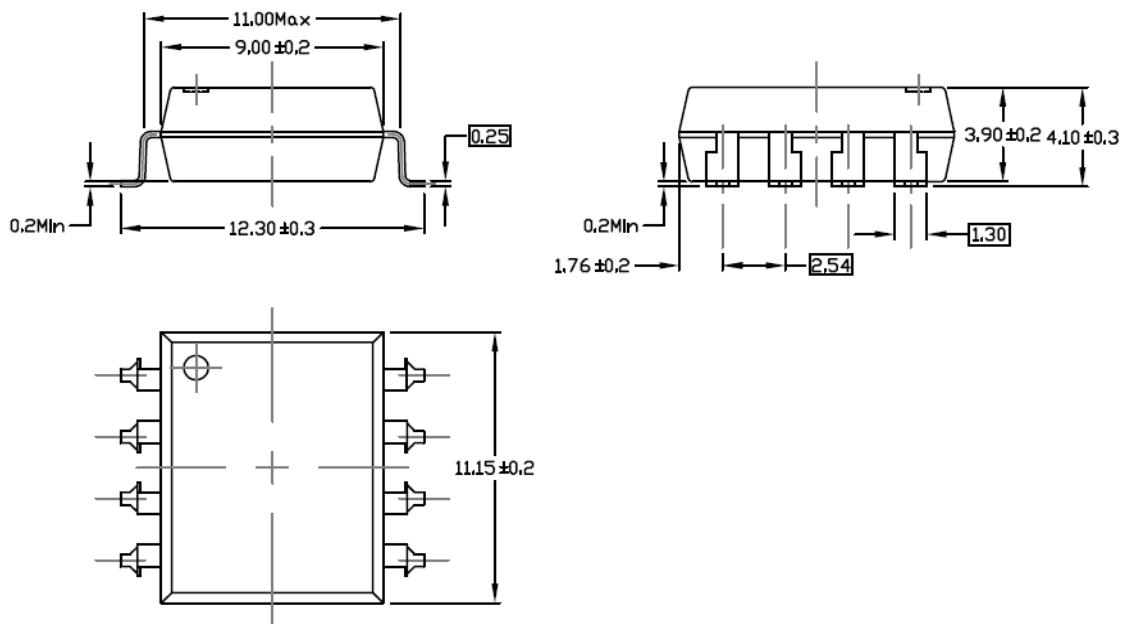
**Package Drawing**

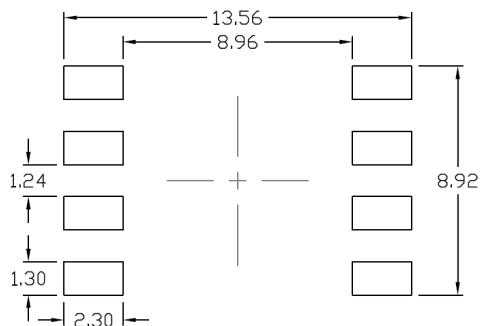
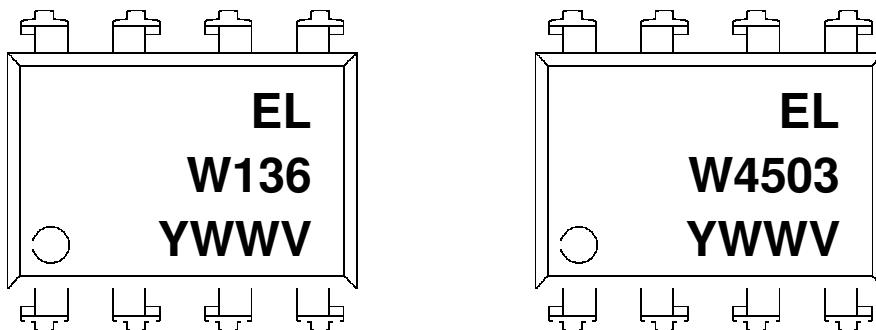
(Dimensions in mm)

**Standard DIP Type**



**Option S Type**



**Recommended pad layout for surface mount leadform****Device Marking****Notes**

4503

W136 denotes Device Number

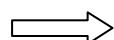
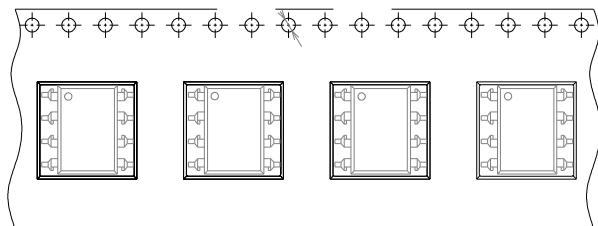
Y denotes 1 digit Year code

WW denotes 2 digit Week code

V denotes VDE (optional)

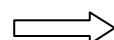
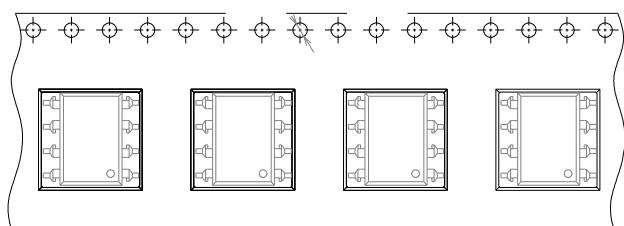
### Tape & Reel Packing Specifications

Option TA



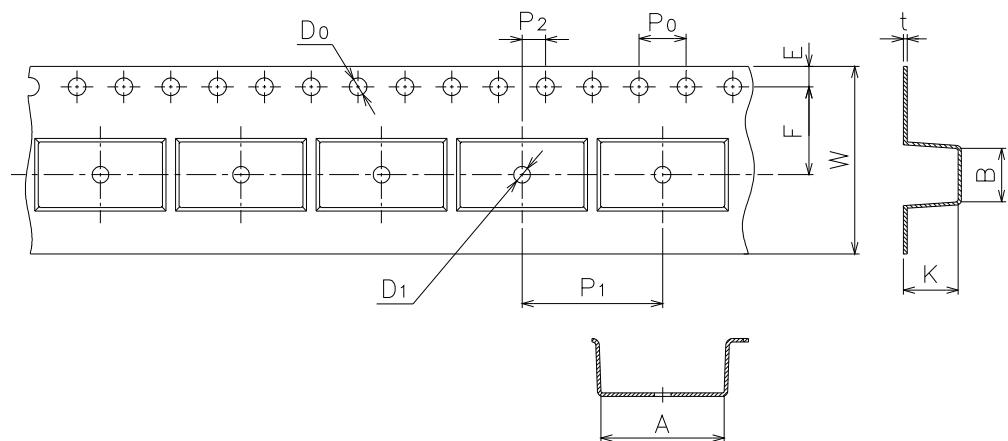
Direction of feed from reel

Option TB

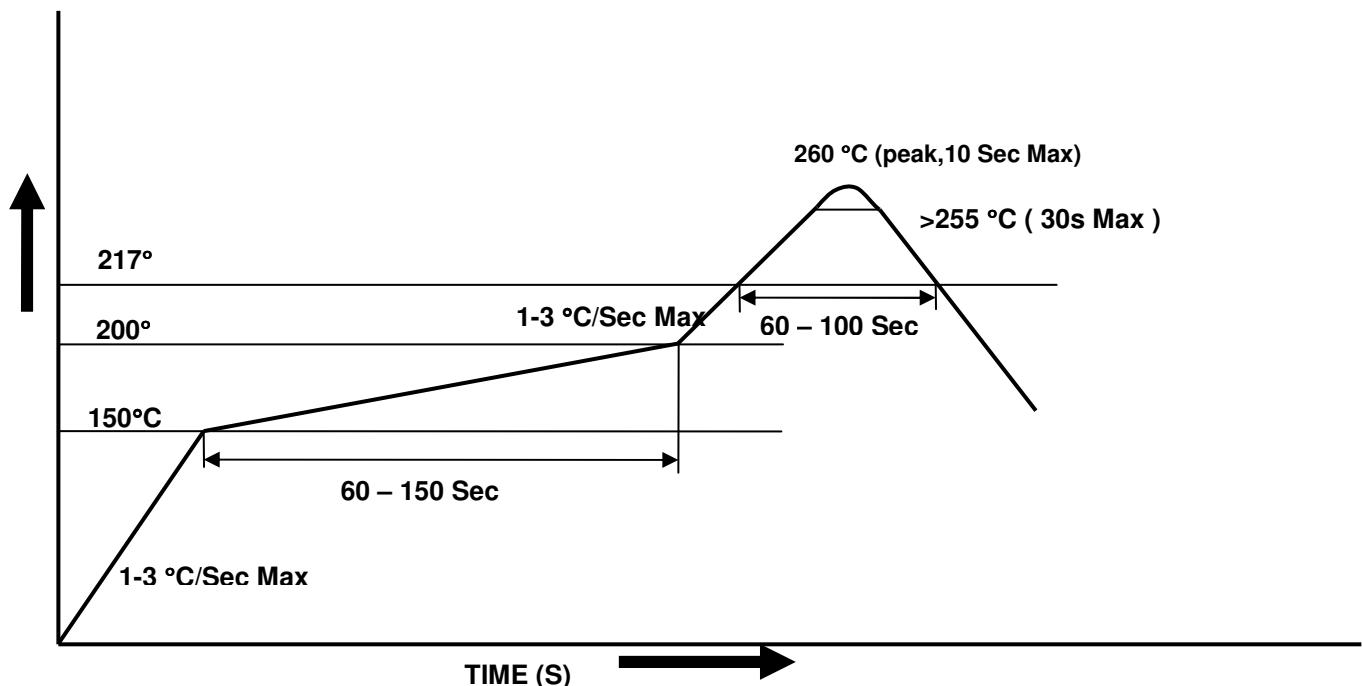


Direction of feed from reel

### Tape dimensions



Dimension No.	<b>A</b>	<b>B</b>	<b>D<sub>0</sub></b>	<b>D<sub>1</sub></b>	<b>E</b>	<b>F</b>
Dimension(mm)	14±0.1	13±0.1	1.5±0.1	1.5±0.1	1.75±0.1	7.5±0.1
Dimension No.	<b>P<sub>0</sub></b>	<b>P<sub>1</sub></b>	<b>P<sub>2</sub></b>	<b>t</b>	<b>W</b>	<b>K</b>
Dimension(mm)	4.0±0.1	12.0±0.1	2.0±0.1	0.4±0.1	16.0+0.3/ -0.1	4.5±0.1

**Solder Reflow Temperature Profile**

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